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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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# **TF252**

# ON Semiconductor®

# N-Channel JFET 20V, 140 to 350μA, 1.4mS, USFP

http://onsemi.com

## **Features**

- High gain : GV=1.0dB typ (VCC=2V, RL=2.2kΩ, Cin=5pF, VIN=10mV, f=1kHz)
- Ultrasmall package facilitates miniaturization in end products [1.0mm×0.6mm×0.27mm (max 0.3mm)]
- Best suited for use in Electret Condenser Microphone for audio equipments and telephones
- · Excellent voltage characteristics
- · Excellent transient characteristics
- · Adoption of FBET process
- · Halogen free compliance
- · Protection diode in

# **Specifications**

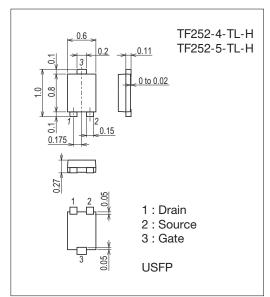
# Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Gate-to-Drain Voltage	V <sub>GDO</sub>		-20	V
Gate Current	IG		10	mA
Drain Current	ID		1	mA
Allowable Power Dissipation	PD		30	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

## **Package Dimensions**

unit : mm (typ) 7055-001



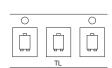
## **Product & Package Information**

• Package : USFP

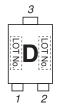
• JEITA, JEDEC : -

• Minimum Packing Quantity : 10,000 pcs./reel

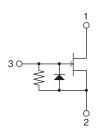
#### Packing Type: TL



# Marking



#### **Electrical Connection**



#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions		Ratings			
Parameter Symbol		Conditions	min	typ	max	Unit	
Gate-to-Drain Breakdown Voltage	V(BR)GDO	IG=-100μA	-20			V	
Cutoff Voltage	VGS(off)	V <sub>DS</sub> =2V, I <sub>D</sub> =1μA	-0.1	-0.4	-1.0	V	
Drain Current	IDSS	V <sub>DS</sub> =2V, V <sub>GS</sub> =0V	140*		350*	μΑ	
Forward Transfer Admittance	yfs	V <sub>DS</sub> =2V, V <sub>GS</sub> =0V, f=1kHz	0.8	1.4		mS	
Input Capacitance	Ciss	VDQ 2V VQQ 0V f 1MLI=		3.1		pF	
Reverse Transfer Capacitance	Crss	VDS=2V, VGS=0V, f=1MHz		0.95		pF	
[Ta=25°C, V <sub>CC</sub> =2V, R <sub>L</sub> =2.2kΩ, Cin=5pF, Se	[Ta=25°C, V <sub>CC</sub> =2V, R <sub>L</sub> =2.2kΩ, Cin=5pF, See specified Test Circuit.]						
Voltage Gain	Gy	V <sub>IN</sub> =10mV, f=1kHz		1.0		dB	
Reduced Voltage Characteristic	ΔGVV	V <sub>IN</sub> =10mV, f=1kHz, V <sub>C</sub> C=2.0V → 1.5V		-0.6	-2.0	dB	
Frequency Characteristic	∆Gvf	f=1kHz to 110Hz	-1		-1.0	dB	
Total Harmonic Distortion	THD	V <sub>IN</sub> =30mV, f=1kHz		0.65		%	
Output Noise Voltage	VNO	V <sub>IN</sub> =0V, A curve		-106	-102	dB	

 $^{\star}$  : The TF252 is classified by IDSS as follows : (unit :  $\mu A)$ 

Rank	4	5	
IDSS	140 to 240	210 to 350	

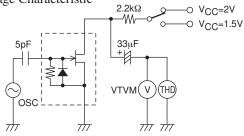
#### **Test Circuit**

Voltage gain

Frequency Characteristic

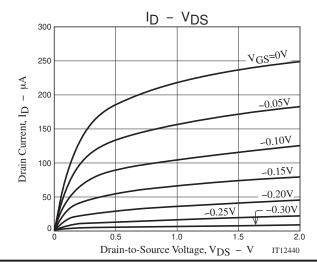
Distortion

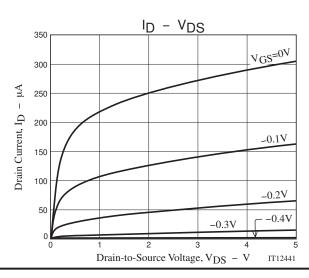
Reduced Voltage Characteristic

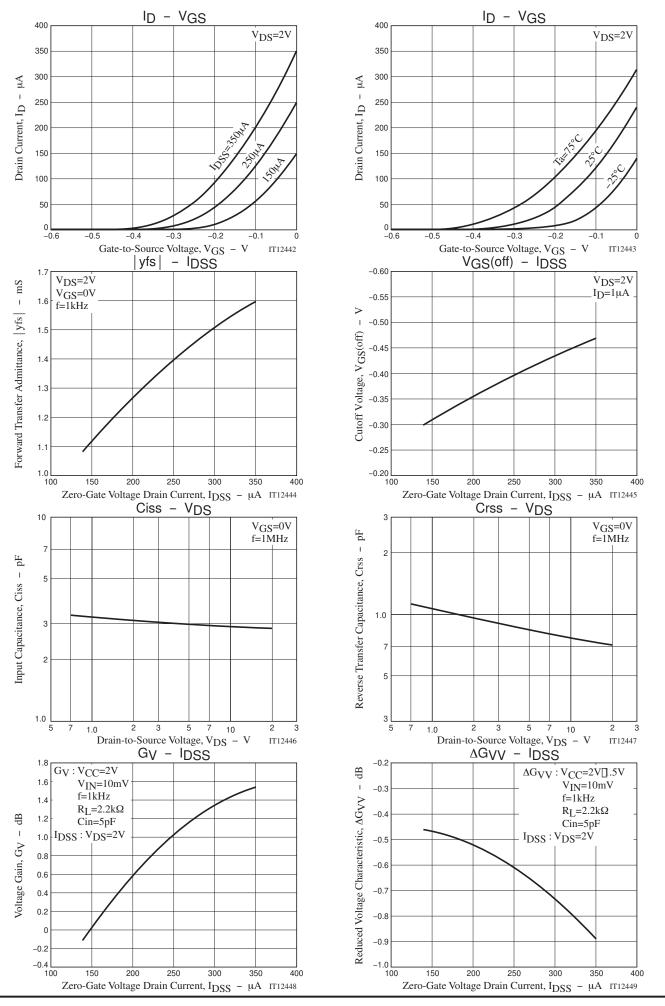


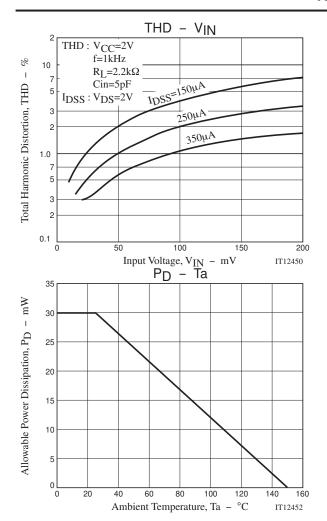
# **Ordering Information**

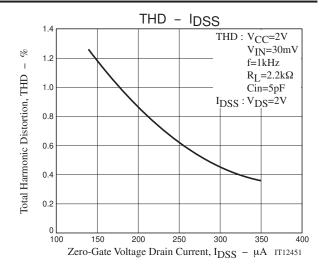
Device	Package	Package Shipping	
TF252-4-TL-H	USFP	10,000pcs./reel	Db Free and Helegen Free
TF252-5-TL-H	USFP	10,000pcs./reel	Pb Free and Halogen Free









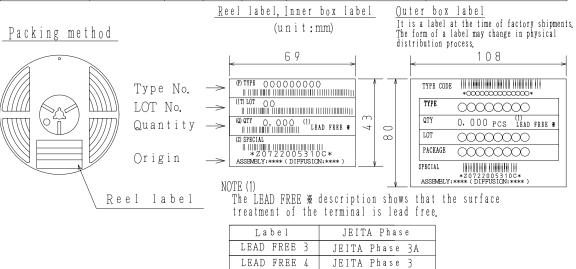


#### **Taping Specification**

#### TF252-4-TL-H, TF252-5-TL-H

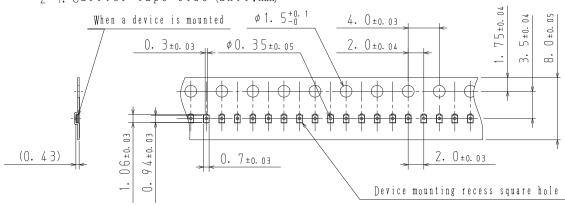
## 1. Packing Format

Package Name	Carrier Tape	Maximum Number of devices contained (pcs)			Packing	format
	Туре	Reel	Inner box	Outer box	Inner $BOX(C-1)$	Outer BOX (A-7)
USFP	USFP	10,000	50,000	300,000	5 reels contained	6 inner boxes contained
					Dimensions:mm (external)	Dimensions:mm (external)
					183×72×185	440×195×210

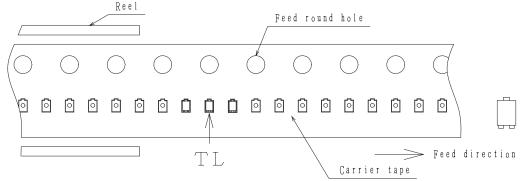


# 2. Taping configuration

2-1. Carrier tape size (unit:mm)



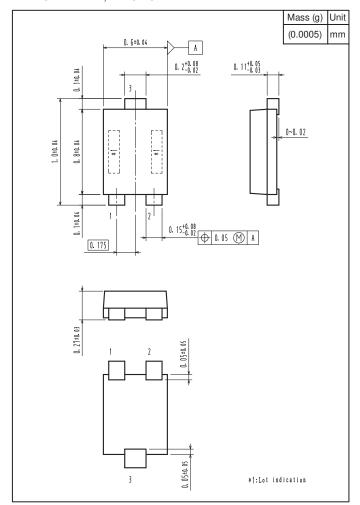
7-7. Device placement direction



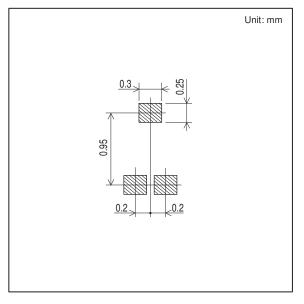
Those with one electrode terminal on the feed hole side·····TL

# **Outline Drawing**

TF252-4-TL-H, TF252-5-TL-H



# **Land Pattern Example**



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